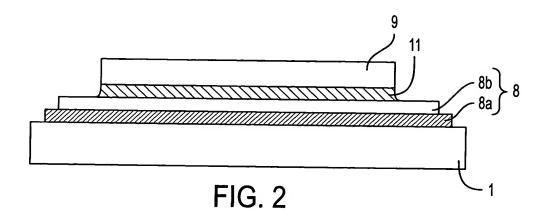
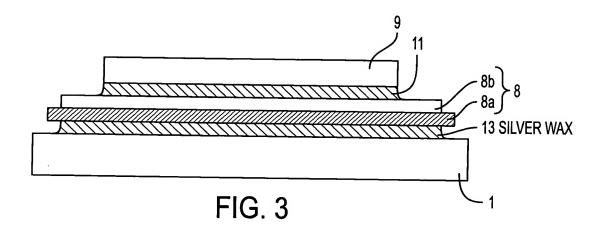
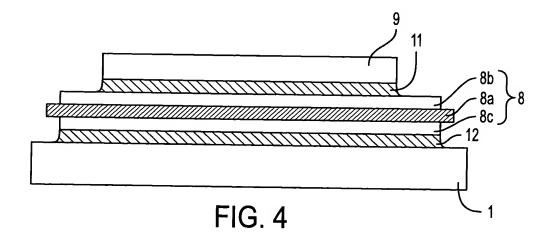


A 8

FIG. 1b







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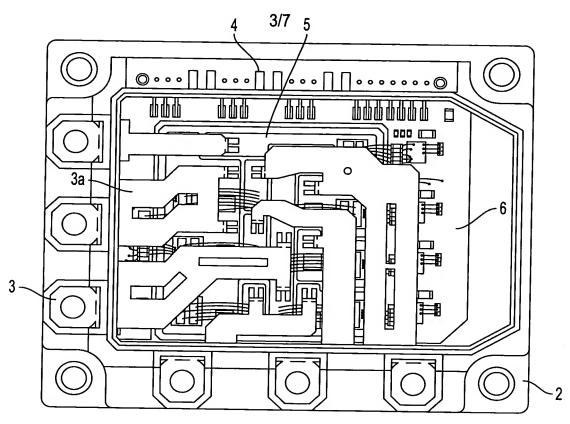


FIG. 5a

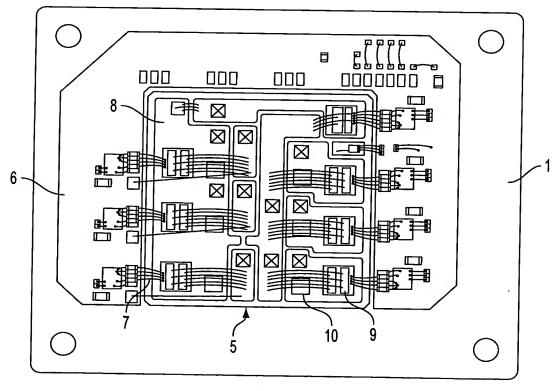


FIG. 5b

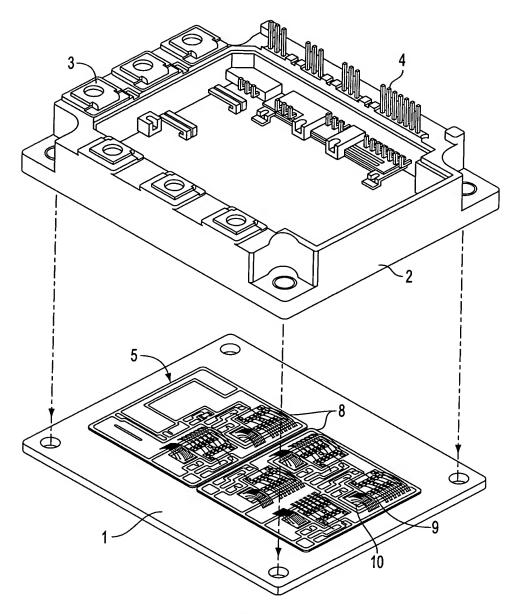


FIG. 6a

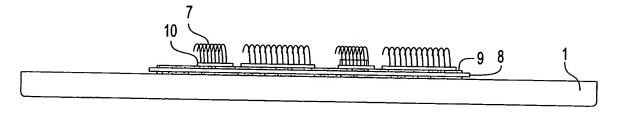


FIG. 6b

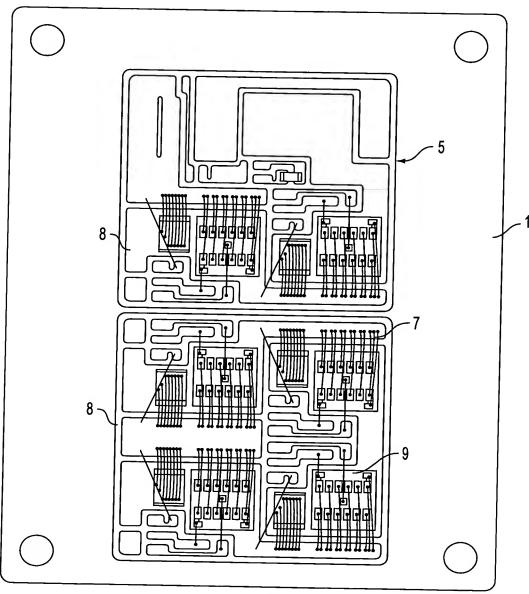


FIG. 7a

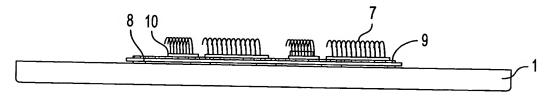
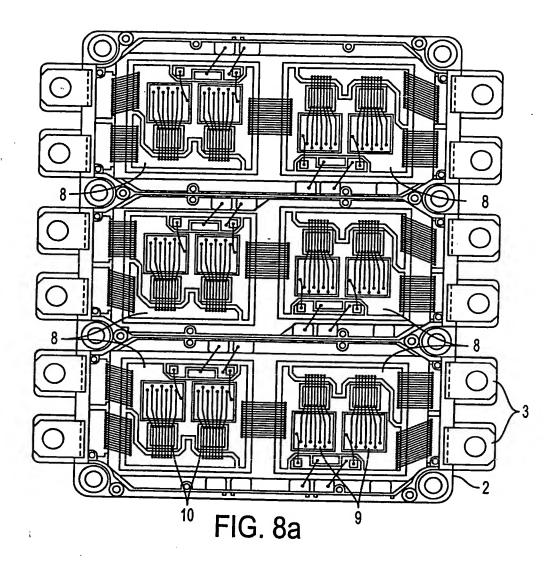
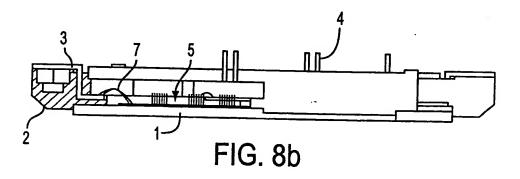


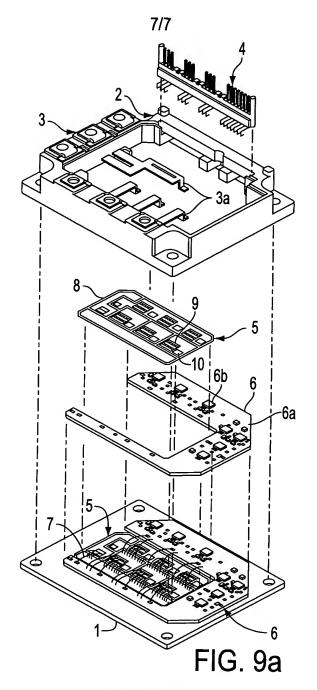
FIG. 7b

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TITLE: POWER SEMICONDUCTOR MODULE INVENTORS: Takatoshi KOBAYASHI, et al. SERIAL NO.: Unassigned DOCKET NO.: 1639.1001D



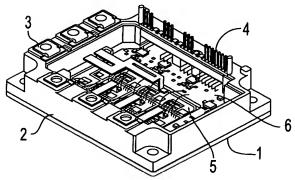


FIG. 9b